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	Claim Amendment
	1-4. (canceled)
المحار	5. (previously amended) A structure of claim 17, wherein the drain contact region is split
	drain contact portion.
	6. (canceled)
<u> </u>	7. (previously amended) A structure of claim 17, wherein the structure includes multiple
Sylo	emitters outside at least part of the drain contact region.
1-	8-10. (withdrawn)
- (11. (currently amended) A high holding voltage LVTSCR-like structure, comprising
YD,	an emitter,
)	a drain contact region, and
12	\ a floating drain, wherein the emitter is located so that at least part of the drain
	contact region is located between the a gate and the emitter.
	\mathcal{X}
	12. (currently amended) A structure of claim 11, wherein the drain <u>contact region</u> is split
	into at least one first drain portion located near the gate, and at least one second drain portion.
	T3. (canceled)
	14. (original) A structure of claim11, wherein the emitter comprises a plurality of
US	amitter regions.
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h	15. (original) A structure of claim 12, wherein the emitter comprises a plurality of
V	emitter regions.
- 100	A structure of claim 12, wherein the floating drain and drain
3 pm	contact region are separated by a shallow trench isolation region.
4 (17. (previously added) A LVTSCR-like ESD protection structure, comprising

P05013

a gate, wherein at least part of the drain contact region is located between the p+

a drain contact region, a p+ emitter, and

emitter and the gate.

Missing

(previously added) A structure of claim 17, further comprising a floating drain located between the gate and the p+ emitter.

P05013